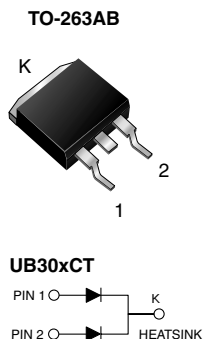
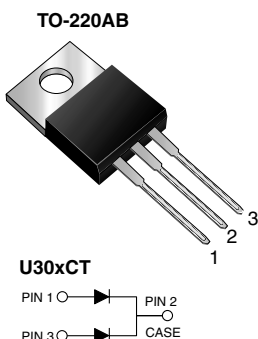




## Dual Common-Cathode Ultrafast Plastic Rectifier



## FEATURES

- Oxide planar chip junction
- Ultrafast recovery time
- Soft recovery characteristics
- Low switching losses, high efficiency
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

RoHS  
COMPLIANT

## TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching power supplies, freewheeling diodes, dc-to-dc converters or polarity protection specifically for CCM application.

## MECHANICAL DATA

**Case:** TO-220AB and TO-263AB

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

## PRIMARY CHARACTERISTICS

|                       |                     |
|-----------------------|---------------------|
| $I_{F(AV)}$           | 2 x 15 A            |
| $V_{RRM}$             | 100 V, 150 V, 200 V |
| $I_{FSM}$             | 160 A               |
| $t_{rr}$              | 17 ns               |
| $V_F$ at $I_F = 15$ A | 0.892 V             |
| $T_J$ max.            | 150 °C              |

MAXIMUM RATINGS ( $T_C = 25$  °C unless otherwise noted)

| PARAMETER                                                                                                     | SYMBOL         | U(B)30BCT     | U(B)30CCT | U(B)30DCT | UNIT |
|---------------------------------------------------------------------------------------------------------------|----------------|---------------|-----------|-----------|------|
| Maximum repetitive peak reverse voltage                                                                       | $V_{RRM}$      | 100           | 150       | 200       | V    |
| Max. average forward rectified current<br>(Fig. 1)                                                            | $I_{F(AV)}$    | 30<br>15      |           |           | A    |
| Peak forward surge current single half sine-wave<br>superimposed on rated load per diode                      | $I_{FSM}$      | 160<br>150    |           |           | A    |
| Electrostatic discharge capacitor voltage,<br>human body model: C = 150 pF, R = 1.5 k $\Omega$ (contact mode) | $V_C$          | 8             |           |           | kV   |
| Operating junction and storage temperature range                                                              | $T_J, T_{STG}$ | - 55 to + 150 |           |           | °C   |

| ELECTRICAL CHARACTERISTICS ( $T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted) |                                                                                                                   |                                                                           |          |                |           |               |
|-----------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------|----------|----------------|-----------|---------------|
| PARAMETER                                                                               | TEST CONDITIONS                                                                                                   |                                                                           | SYMBOL   | TYP.           | MAX.      | UNIT          |
| Instantaneous forward voltage per diode <sup>(1)</sup>                                  | $I_F = 7.5\text{ A}$<br>$I_F = 15\text{ A}$                                                                       | $T_J = 25\text{ }^{\circ}\text{C}$                                        | $V_F$    | 0.875<br>0.964 | -<br>1.05 | V             |
|                                                                                         | $I_F = 7.5\text{ A}$<br>$I_F = 15\text{ A}$                                                                       | $T_J = 100\text{ }^{\circ}\text{C}$                                       |          | 0.800<br>0.892 | -<br>0.95 |               |
| Reverse current per diode <sup>(2)</sup>                                                | rated $V_R$                                                                                                       | $T_J = 25\text{ }^{\circ}\text{C}$<br>$T_J = 100\text{ }^{\circ}\text{C}$ | $I_R$    | 1.3<br>200     | 20<br>600 | $\mu\text{A}$ |
| Reverse recovery time per diode                                                         | $I_F = 0.5\text{ A}$ , $I_R = 1.0\text{ A}$ , $I_{rr} = 0.25\text{ A}$                                            |                                                                           | $t_{rr}$ | 17             | 25        | ns            |
| Reverse recovery time per diode                                                         | $I_F = 15\text{ A}$ , $dI/dt = 200\text{ A}/\mu\text{s}$ ,<br>$V_R = 200\text{ V}$ , $I_{rr} = 0.1\text{ I}_{RM}$ |                                                                           | $t_{rr}$ | 36             | 45        | ns            |
| Stored charge per diode                                                                 |                                                                                                                   |                                                                           | $Q_{rr}$ | 110            | -         | nC            |
| Forward recovery time per diode                                                         | $I_F = 15\text{ A}$ , $dI/dt = 120\text{ A}/\mu\text{s}$ ,<br>$V_F = 1.1 \times V_{F\text{ max.}}$                |                                                                           | $t_{fr}$ | 175            | -         | ns            |
| Peak forward voltage per diode                                                          |                                                                                                                   |                                                                           | $V_{FP}$ | 3.1            | -         | V             |

**Notes:**

(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq 40\text{ ms}$

| THERMAL CHARACTERISTICS ( $T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted) |                 |        |         |                             |
|--------------------------------------------------------------------------------------|-----------------|--------|---------|-----------------------------|
| PARAMETER                                                                            | SYMBOL          | U30xCT | UB30xCT | UNIT                        |
| Typical thermal resistance per diode                                                 | $R_{\theta JC}$ | 2.4    |         | $^{\circ}\text{C}/\text{W}$ |

| ORDERING INFORMATION (Example) |               |             |              |               |               |
|--------------------------------|---------------|-------------|--------------|---------------|---------------|
| PACKAGE                        | PREFERRED P/N | UNIT WEIGHT | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
| TO-220AB                       | U30DCT-E3/4W  | 1.87        | 4W           | 50/tube       | Tube          |
| TO-263AB                       | UB30DCT-E3/4W | 1.37        | 4W           | 50/tube       | Tube          |
| TO-263AB                       | UB30DCT-E3/8W | 1.37        | 8W           | 800/reel      | Tape and reel |

## RATINGS AND CHARACTERISTICS CURVES

( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

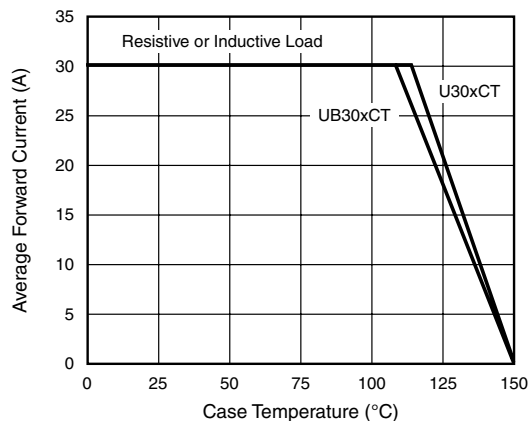


Figure 1. Maximum Forward Current Derating Curve

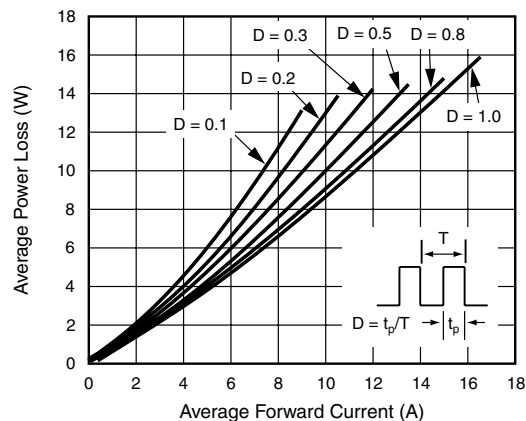


Figure 2. Forward Power Loss Characteristics Per Diode

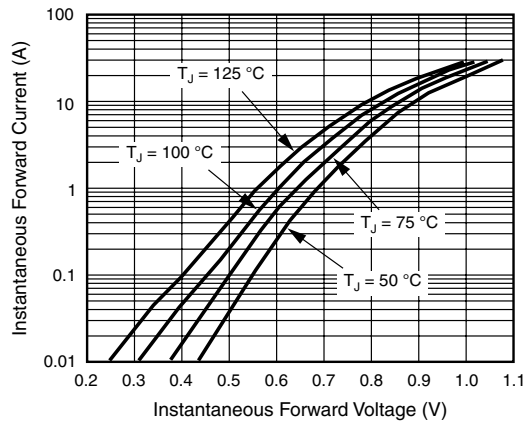


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

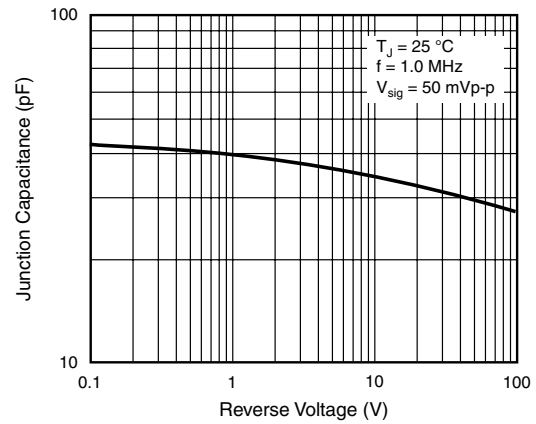


Figure 5. Typical Junction Capacitance Per Diode

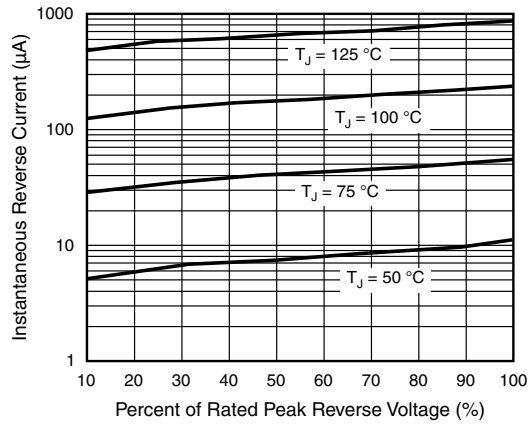


Figure 4. Typical Reverse Characteristics Per Diode

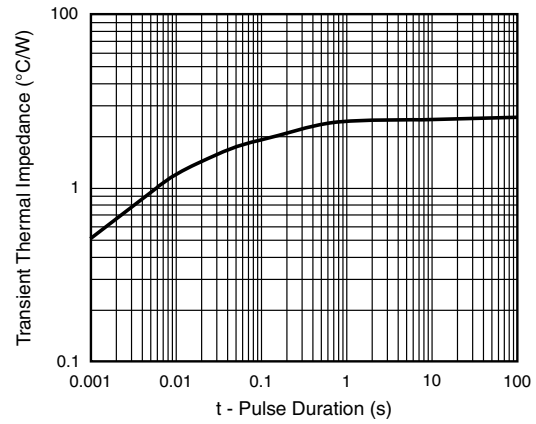


Figure 6. Typical Junction Capacitance Per Diode

# U(B)30BCT thru U(B)30DCT

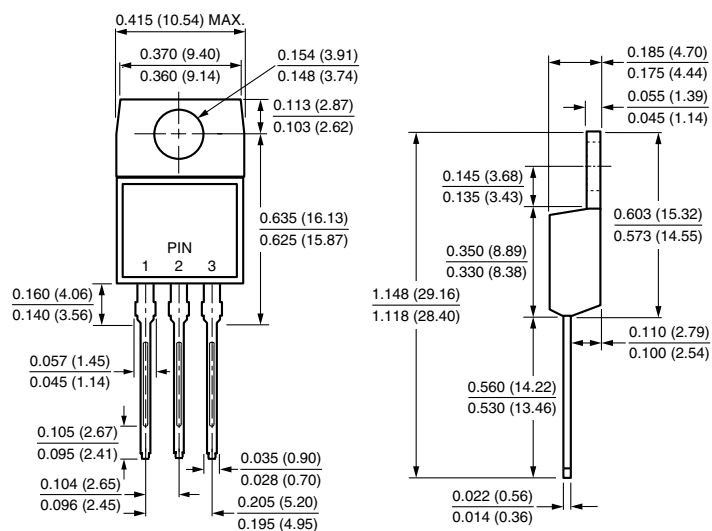
New Product

Vishay General Semiconductor

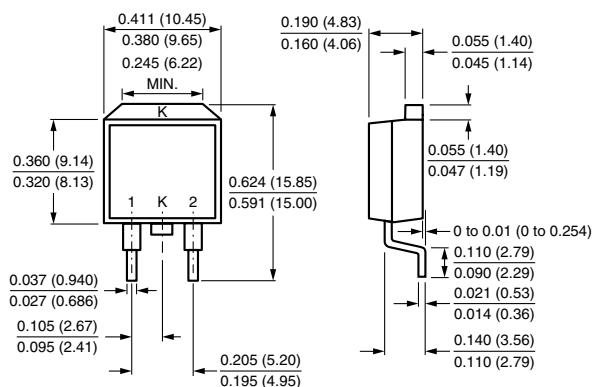


## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

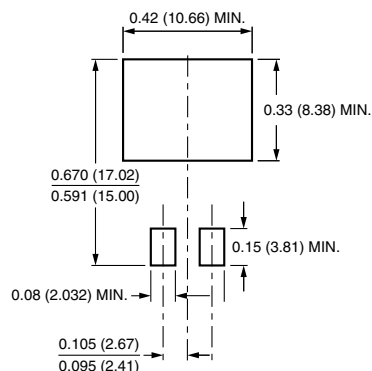
TO-220AB



TO-263AB



Mounting Pad Layout





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